# 2026 IEEE Topical Conference on RF/Microwave Power Amplifiers for Radio and Wireless Applications (PAWR 2026)

## Hollywood, California, USA
## 18-21 January 2026

IEEE Catalog Number: CFP26PAR-POD
ISBN: 979-8-3315-6161-1

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| | |
|---|---|
| IEEE Catalog Number: | CFP26PAR-POD |
| ISBN (Print-On-Demand): | 979-8-3315-6161-1 |
| ISBN (Online): | 979-8-3315-6160-4 |
| ISSN: | 2164-8751 |

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